

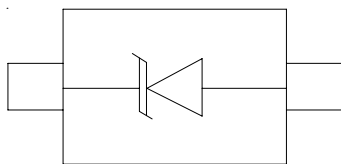
## Description

The DC1501D5 is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and ultra low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The DC1501D5 complies with the IEC 61000-4-2 (ESD) with  $\pm 30\text{kV}$  air and  $\pm 30\text{kV}$  contact discharge. It is assembled into an ultra-small SOD-523 lead-free package. The small size and high ESD surge protection make DC1501D5 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

## Mechanical Characteristics

- ◆ Package: SOD-523
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: "Green" Molding Compound.
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

## Dimensions and Pin Configuration



Circuit and Pin Schematic

## Features

- ◆ Protects one line
- ◆ Ultra low leakage: nA level
- ◆ Operating voltage: 15V
- ◆ Low clamping voltage
- ◆ Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge:  $\pm 30\text{kV}$
    - Contact discharge:  $\pm 30\text{kV}$
  - IEC61000-4-5 (Lightning) 10A (8/20 $\mu\text{s}$ )
- ◆ ROHS Compliant

## Applications

- ◆ Cellular Handsets and Accessories
- ◆ Personal Digital Assistants
- ◆ Notebooks, Desktops, Servers
- ◆ Portable Instrumentation
- ◆ Printers
- ◆ Analog Inputs
- ◆ Video equipment
- ◆ Communication systems
- ◆ Laser Diode Protection

## Marking Information



15E = Device Marking Code  
Bar denotes Cathode

## Ordering Information

Part Number	Marking	Packaging	Reel Size
DC1501D5	15E	3000/Tape & Reel	7 inch

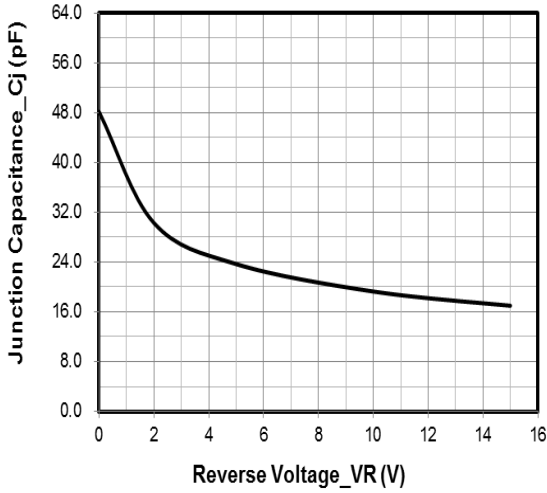
### **Absolute Maximum Ratings ( $T_A=25^{\circ}\text{C}$ unless otherwise specified)**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 $\mu\text{s}$ )	Ppk	300	W
Peak Pulse Current (8/20 $\mu\text{s}$ )	Ipp	10	A
ESD per IEC 61000-4-2 (Air)	VESD	$\pm 30$	kV
ESD per IEC 61000-4-2 (Contact)		$\pm 30$	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}\text{C}$

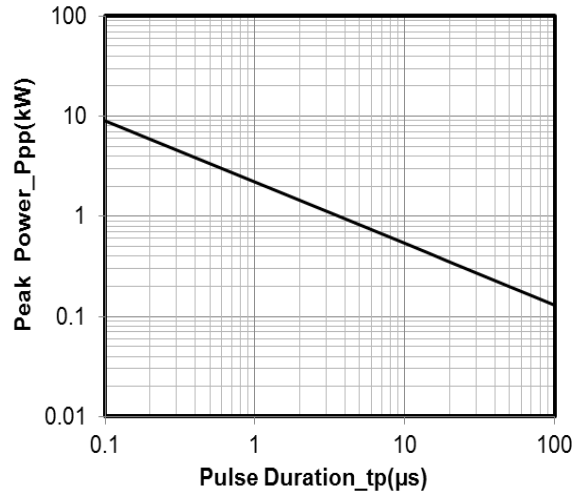
### **Electrical Characteristics ( $T_A=25^{\circ}\text{C}$ unless otherwise specified)**

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			15	V	
Breakdown Voltage	VBR	18			V	$I_T = 1\text{mA}$
Reverse Leakage Current	$I_R$			0.2	$\mu\text{A}$	$VRWM = 15\text{V}$
Clamping Voltage	$V_C$			23	V	$I_{PP} = 1\text{A}$ (8 x 20 $\mu\text{s}$ pulse)
Clamping Voltage	$V_C$			32	V	$I_{PP} = 10\text{A}$ (8 x 20 $\mu\text{s}$ pulse)
Junction Capacitance	CJ			60	pF	$V_R = 0\text{V}$ , $f = 1\text{MHz}$

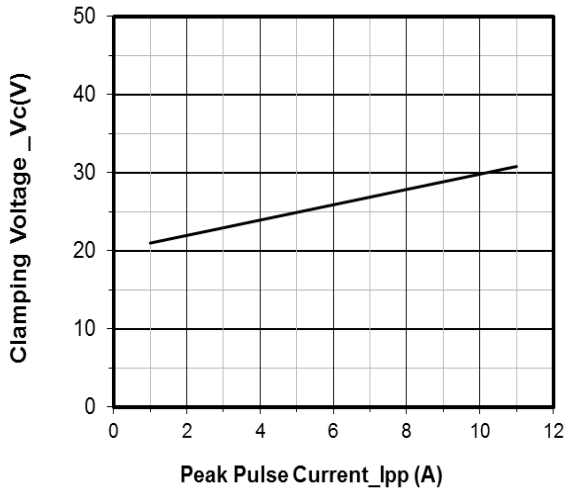
**Typical Performance Characteristics (TA=25°C unless otherwise Specified)**



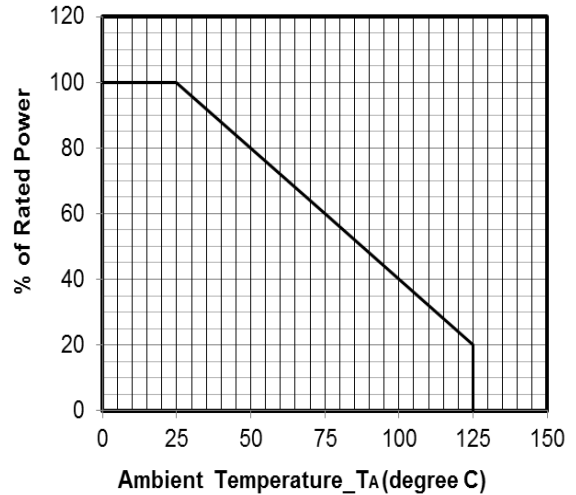
**Junction Capacitance vs. Reverse Voltage**



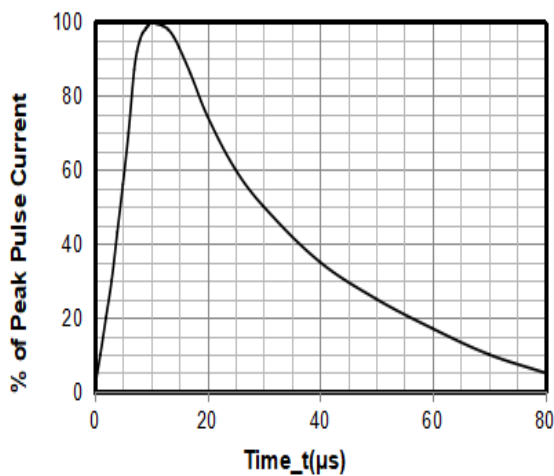
**Peak Pulse Power vs. Pulse Time**



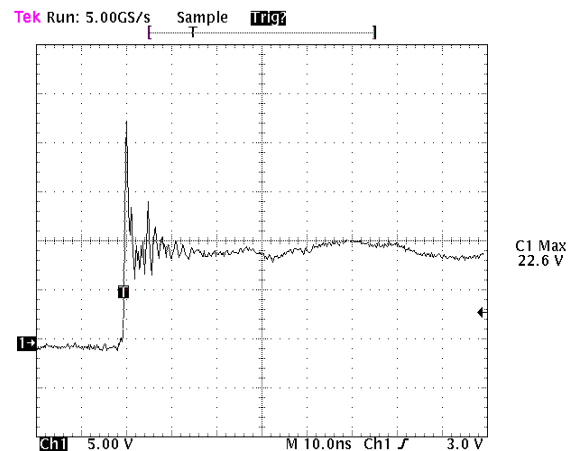
**Clamping Voltage vs. Peak Pulse Current**



**Power Derating Curve**

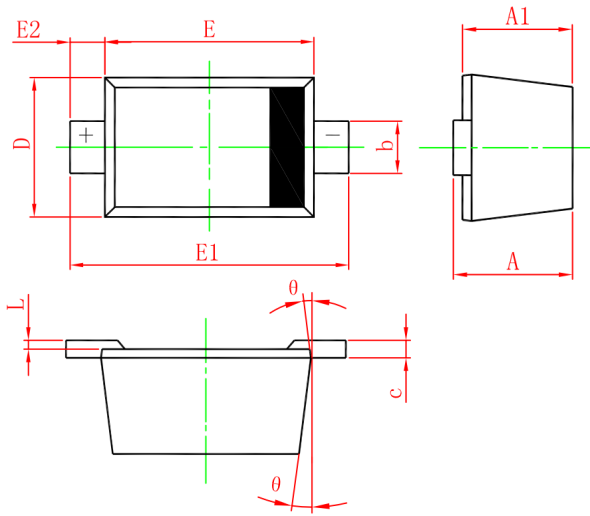


**8 X 20μs Pulse Waveform**



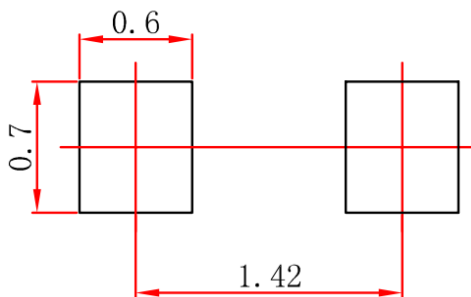
Note: Data is taken with a 10x attenuator  
**ESD Clamping Voltage**  
**+8 kV Contact per IEC61000-4-2**

## SOD-523 Package Outline Drawing



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.51	--	0.77	0.020	--	0.031
A1	0.50	--	0.70	0.020	--	0.028
b	0.25	--	0.35	0.010	--	0.014
c	0.08	--	0.15	0.003	--	0.006
D	0.75	--	0.85	0.030	--	0.033
E	1.10	--	1.30	0.043	--	0.051
E1	1.50	--	1.70	0.059		0.067
E2	0.20REF			0.008REF		
L	0.01	--	0.07	0.001	--	0.003
Θ	7° REF			7° REF		

## Suggested Land Pattern



Unit : mm

## Contact Information

Changzhou D-first Electronics CO.,Ltd.

www.first-electronic.com

Email: xhf@first-electronic.cn

Phone: +86 (0519) -8817 1671